## NSN 5962-01-422-0377

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Maximum Power Dissipation Rating:
1.000 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Current Rating Per Characteristic:
50.00 milliamperes peak forward surge current horsepower metric
Voltage Rating And Type Per Characteristic:
4.5 volts power source and 5.5 volts power source
Capitance Rating Per Characteristic:
8.000 input picofarads
Time Rating Per Chacteristic:
80.000 nanoseconds access
Memory Device Type:
First-in first-out
Hybrid Technology Type:
Monolithic
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0